

# $\mu$ A78M00 SERIES POSITIVE-VOLTAGE REGULATORS

SLVS059D – JUNE 1976 – REVISED JULY 1999

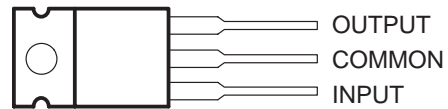
- 3-Terminal Regulators
- Output Current up to 500 mA
- No External Components
- Internal Thermal-Overload Protection
- High Power-Dissipation Capability
- Internal Short-Circuit Current Limiting
- Output Transistor Safe-Area Compensation
- Direct Replacements for Fairchild  $\mu$ A78M00 Series

## description

This series of fixed-voltage integrated-circuit voltage regulators is designed for a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. Each of these regulators can deliver up to 500 mA of output current. The internal current-limiting and thermal-shutdown features of these regulators essentially make them immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents and also as the power-pass element in precision regulators.

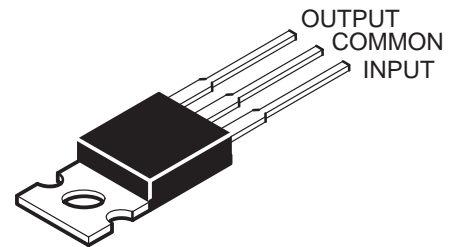
The  $\mu$ A78M00C series is characterized for operation over the virtual junction temperature range of 0°C to 125°C.

KC PACKAGE  
(TOP VIEW)

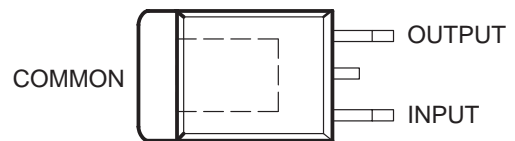


The COMMON terminal is in electrical contact with the mounting base.

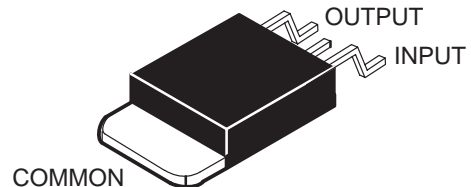
TO-220AB



KTP PACKAGE  
(TOP VIEW)



The COMMON terminal is in electrical contact with the mounting base.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

 **TEXAS  
INSTRUMENTS**

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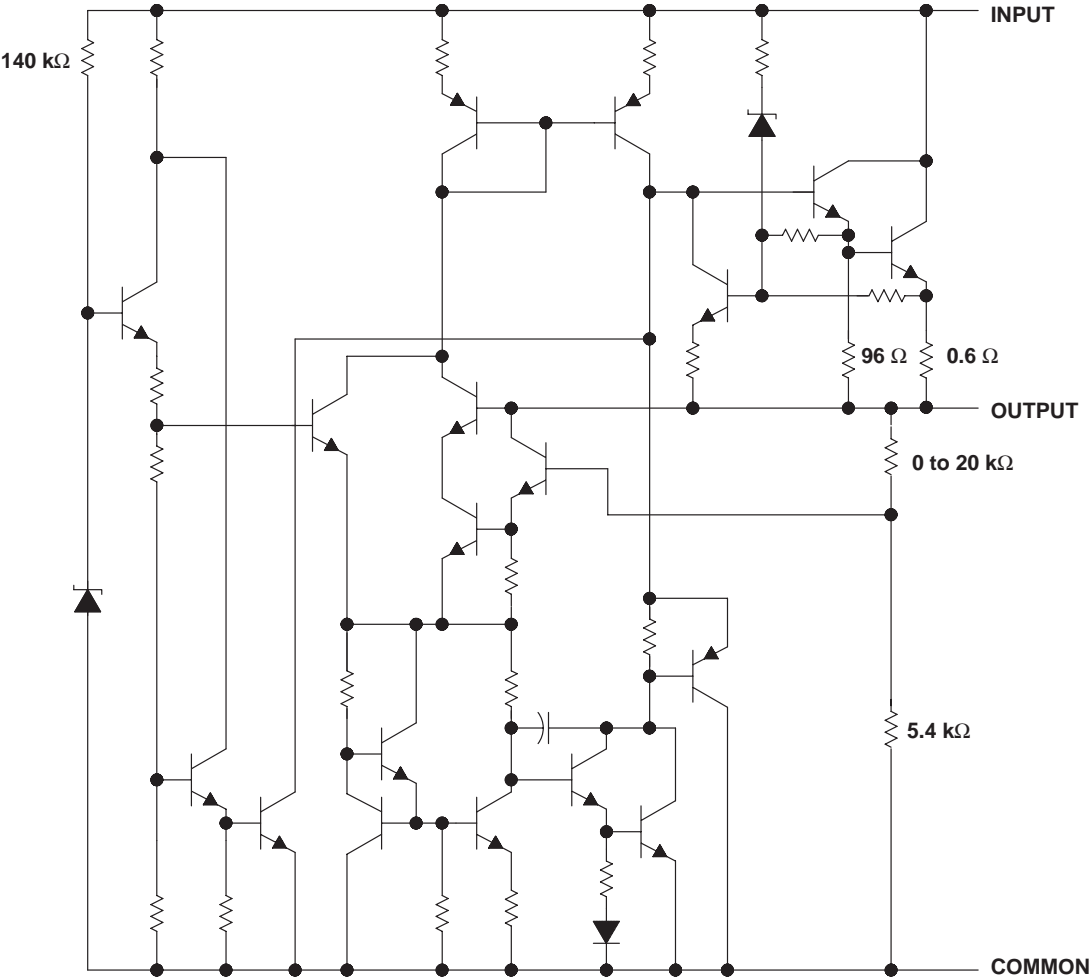
μA78M00 SERIES  
 POSITIVE-VOLTAGE REGULATORS

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AVAILABLE OPTIONS				
T <sub>J</sub>	V <sub>O(NOM)</sub> (V)	PACKAGED DEVICES		CHIP FORM (Y)
		HEAT-SINK MOUNTED (KC)	PLASTIC FLANGE MOUNTED (KTP)	
0°C to 125°C	5	μA78M05CKC	μA78M05CKTP	μA78M05Y
	6	μA78M06CKC	μA78M06CKTP	μA78M06Y
	8	μA78M08CKC	μA78M08CKTP	μA78M08Y
	9	μA78M09CKC	μA78M09CKTP	μA78M09Y
	10	μA78M10CKC	μA78M10CKTP	μA78M10Y
	12	μA78M12CKC	μA78M12CKTP	μA78M12Y
	15	μA78M15CKC	μA78M15CKTP	μA78M15Y
	20	μA78M20CKC	μA78M20CKTP	μA78M20Y
	24	μA78M24CKC	μA78M24CKTP	μA78M24Y

The KTP package is only available taped and reeled. Add the suffix R to the device type (e.g., μA78M05CKTPR). Chip forms are tested at 25°C.

schematic



Resistor values shown are nominal.

**absolute maximum ratings over operating temperature range (unless otherwise noted)<sup>†</sup>**

	μA78Mxx	UNIT
Input voltage, $V_I$	μA78M20, μA78M24	40
	All others	35
Package thermal impedance, $\theta_{JA}$ (see Notes 1 and 2)	KC package	22
	KTP package	28
Virtual junction temperature range, $T_J$	0 to 150	°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260	°C
Storage temperature range, $T_{stg}$	–65 to 150	°C

<sup>†</sup> Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. Maximum power dissipation is a function of  $T_J(\text{max})$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(\text{max}) - T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can impact reliability. Due to variations in individual device electrical characteristics and thermal resistance, the built-in thermal-overload protection may be activated at power levels slightly above or below the rated dissipation.
2. The package thermal impedance is calculated in accordance with JEDEC 51, except for through-hole packages, which use a trace length of zero.

**recommended operating conditions**

		MIN	MAX	UNIT
Input voltage, $V_I$	μA78M05	7	25	V
	μA78M06	8	25	
	μA78M08	10.5	25	
	μA78M09	11.5	26	
	μA78M10	12.5	28	
	μA78M12	14.5	30	
	μA78M15	17.5	30	
	μA78M20	23	35	
	μA78M24	27	38	
Output current, $I_O$			500	mA
Operating virtual junction temperature, $T_J$		0	125	°C

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**electrical characteristics at specified virtual junction temperature,  $V_I = 10\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†	μA78M05C			UNIT
		MIN	TYP	MAX	
Output voltage	$V_I = 7\text{ V to }20\text{ V}$ $T_J = 0^\circ\text{C to }125^\circ\text{C}$	4.8	5	5.2	V
		4.75		5.25	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 7\text{ V to }25\text{ V}$	3	100	mV
		$V_I = 8\text{ V to }20\text{ V}$			
		$V_I = 8\text{ V to }25\text{ V}$	1	50	
Ripple rejection	$V_I = 8\text{ V to }18\text{ V}$ , $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$		62	dB
		$I_O = 300\text{ mA}$		62 80	
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		20	100	mV
	$I_O = 5\text{ mA to }200\text{ mA}$		10	50	
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$		–1		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		40	200	μV
Dropout voltage			2		V
Bias current			4.5	6	mA
Bias current change	$I_O = 200\text{ mA}$ , $V_I = 8\text{ V to }25\text{ V}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$			0.8	mA
	$I_O = 5\text{ mA to }350\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$			0.5	
Short-circuit output current	$V_I = 35\text{ V}$		300		mA
Peak output current			0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.

**electrical characteristics at specified virtual junction temperature,  $V_I = 11\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†	μA78M06C			UNIT
		MIN	TYP	MAX	
Output voltage	$I_O = 5\text{ mA to }350\text{ mA}$ , $V_I = 8\text{ V to }21\text{ V}$ $T_J = 0^\circ\text{C to }125^\circ\text{C}$	5.75	6	6.25	V
		5.7		6.3	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 8\text{ V to }25\text{ V}$	5	100	mV
		$V_I = 9\text{ V to }25\text{ V}$	1.5	50	
Ripple rejection	$V_I = 9\text{ V to }19\text{ V}$ , $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$		59	dB
		$I_O = 300\text{ mA}$		59 80	
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		20	120	mV
	$I_O = 5\text{ mA to }200\text{ mA}$		10	60	
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$		–1		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		45		μV
Dropout voltage			2		V
Bias current			4.5	6	mA
Bias current change	$V_I = 9\text{ V to }25\text{ V}$ , $I_O = 200\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$			0.8	mA
	$I_O = 5\text{ mA to }350\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$			0.5	
Short-circuit output current	$V_I = 35\text{ V}$		270		mA
Peak output current			0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.



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**electrical characteristics at specified virtual junction temperature,  $V_I = 14\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†		μA78M08C			UNIT
			MIN	TYP	MAX	
Output voltage	$V_I = 10.5\text{ V to }23\text{ V}$ , $I_O = 5\text{ mA to }350\text{ mA}$		7.7	8	8.3	V
		$T_J = 0^\circ\text{C to }125^\circ\text{C}$	7.6		8.4	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 10.5\text{ V to }25\text{ V}$		6	100	mV
		$V_I = 11\text{ V to }25\text{ V}$		2	50	
Ripple rejection	$V_I = 11.5\text{ V to }21.5\text{ V}$ , $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$	56			dB
		$I_O = 300\text{ mA}$	56	80		
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$			25	160	mV
	$I_O = 5\text{ mA to }200\text{ mA}$			10	80	
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$			-1		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$			52		μV
Dropout voltage				2		V
Bias current				4.6	6	mA
Bias current change	$V_I = 10.5\text{ V to }25\text{ V}$ , $I_O = 200\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.8	mA
	$I_O = 5\text{ mA to }350\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.5	
Short-circuit output current	$V_I = 35\text{ V}$			250		mA
Peak output current				0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.

**electrical characteristics at specified virtual junction temperature,  $V_I = 16\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†		μA78M09C			UNIT
			MIN	TYP	MAX	
Output voltage	$V_I = 11.5\text{ V to }24\text{ V}$ , $I_O = 5\text{ mA to }350\text{ mA}$		8.6	9	9.4	V
		$T_J = 0^\circ\text{C to }125^\circ\text{C}$	8.5		9.5	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 11.5\text{ V to }26\text{ V}$		6	100	mV
		$V_I = 12\text{ V to }26\text{ V}$		2	50	
Ripple rejection	$V_I = 13\text{ V to }23\text{ V}$ , $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$	56			dB
		$I_O = 300\text{ mA}$	56	80		
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$			25	180	mV
	$I_O = 5\text{ mA to }200\text{ mA}$			10	90	
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$			-1		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$			58		μV
Dropout voltage				2		V
Bias current				4.6	6	mA
Bias current change	$V_I = 11.5\text{ V to }26\text{ V}$ , $I_O = 200\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.8	mA
	$I_O = 5\text{ mA to }350\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.5	
Short-circuit output current	$V_I = 35\text{ V}$			250		mA
Peak output current				0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.

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**electrical characteristics at specified virtual junction temperature,  $V_I = 17\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†		μA78M10C			UNIT
			MIN	TYP	MAX	
Output voltage	$V_I = 12.5\text{ V to }25\text{ V}$ , $I_O = 5\text{ mA to }350\text{ mA}$		9.6	10	10.4	V
		$T_J = 0^\circ\text{C to }125^\circ\text{C}$	9.5		10.5	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 12.5\text{ V to }28\text{ V}$		7	100	mV
		$V_I = 14\text{ V to }28\text{ V}$		2	50	
Ripple rejection	$V_I = 15\text{ V to }25\text{ V}$ , $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$	59			dB
		$I_O = 300\text{ mA}$	55	80		
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$			25	200	mV
	$I_O = 5\text{ mA to }200\text{ mA}$			10	100	
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$			–1		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$			64		μV
Dropout voltage				2		V
Bias current				4.7	6	mA
Bias current change	$V_I = 12.5\text{ V to }28\text{ V}$ , $I_O = 200\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.8	mA
	$I_O = 5\text{ mA to }350\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.5	
Short-circuit output current	$V_I = 35\text{ V}$			245		mA
Peak output current				0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.

**electrical characteristics at specified virtual junction temperature,  $V_I = 19\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†		μA78M12C			UNIT
			MIN	TYP	MAX	
Output voltage	$V_I = 14.5\text{ V to }27\text{ V}$ , $I_O = 5\text{ mA to }350\text{ mA}$		11.5	12	12.5	V
		$T_J = 0^\circ\text{C to }125^\circ\text{C}$	11.4		12.6	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 14.5\text{ V to }30\text{ V}$		8	100	mV
		$V_I = 16\text{ V to }30\text{ V}$		2	50	
Ripple rejection	$V_I = 15\text{ V to }25\text{ V}$ , $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$	55			dB
		$I_O = 300\text{ mA}$	55	80		
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$			25	240	mV
	$I_O = 5\text{ mA to }200\text{ mA}$			10	120	
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$			–1		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$			75		μV
Dropout voltage				2		V
Bias current				4.8	6	mA
Bias current change	$V_I = 14.5\text{ V to }30\text{ V}$ , $I_O = 200\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.8	mA
	$I_O = 5\text{ mA to }350\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.5	
Short-circuit output current	$V_I = 35\text{ V}$			240		mA
Peak output current				0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.



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**electrical characteristics at specified virtual junction temperature,  $V_I = 23\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†		μA78M15C			UNIT
			MIN	TYP	MAX	
Output voltage	$V_I = 17.5\text{ V to }30\text{ V}$ , $I_O = 5\text{ mA to }350\text{ mA}$	$T_J = 0^\circ\text{C to }125^\circ\text{C}$	14.4	15	15.6	V
			14.25		15.75	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 17.5\text{ V to }30\text{ V}$		10	100	mV
		$V_I = 20\text{ V to }30\text{ V}$		3	50	
Ripple rejection	$V_I = 18.5\text{ V to }28.5\text{ V}$ , $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$	54			dB
		$I_O = 300\text{ mA}$	54	70		
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$			25	300	mV
	$I_O = 5\text{ mA to }200\text{ mA}$			10	150	
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$			–1		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$			90		μV
Dropout voltage				2		V
Bias current				4.8	6	mA
Bias current change	$V_I = 17.5\text{ V to }30\text{ V}$ , $I_O = 200\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.8	mA
	$I_O = 5\text{ mA to }350\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.5	
Short-circuit output current	$V_I = 35\text{ V}$			240		mA
Peak output current				0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.

**electrical characteristics at specified virtual junction temperature,  $V_I = 29\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†		μA78M20C			UNIT
			MIN	TYP	MAX	
Output voltage	$V_I = 23\text{ V to }35\text{ V}$ , $I_O = 5\text{ mA to }350\text{ mA}$	$T_J = 0^\circ\text{C to }125^\circ\text{C}$	19.2	20	20.8	V
			19		21	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 23\text{ V to }35\text{ V}$		10	100	mV
		$V_I = 24\text{ V to }35\text{ V}$		5	50	
Ripple rejection	$V_I = 24\text{ V to }34\text{ V}$ , $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$	53			dB
		$I_O = 300\text{ mA}$	53	70		
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$			30	400	mV
	$I_O = 5\text{ mA to }200\text{ mA}$			10	200	
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$			–1.1		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$			110		μV
Dropout voltage				2		V
Bias current				4.9	6	mA
Bias current change	$V_I = 23\text{ V to }35\text{ V}$ , $I_O = 200\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.8	mA
	$I_O = 5\text{ mA to }350\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.5	
Short-circuit output current	$V_I = 35\text{ V}$			240		mA
Peak output current				0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.

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**electrical characteristics at specified virtual junction temperature,  $V_I = 33\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†		μA78M24C			UNIT
			MIN	TYP	MAX	
Output voltage	$V_I = 27\text{ V to }38\text{ V}$ , $I_O = 5\text{ mA to }350\text{ mA}$	$T_J = 0^\circ\text{C to }125^\circ\text{C}$	23	24	25	V
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 27\text{ V to }38\text{ V}$		10	100	mV
		$V_I = 28\text{ V to }38\text{ V}$		5	50	
Ripple rejection	$V_I = 28\text{ V to }38\text{ V}$ , $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$ , $I_O = 300\text{ mA}$	50			dB
		$T_J = 0^\circ\text{C to }125^\circ\text{C}$	50	70		
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$			30	480	mV
	$I_O = 5\text{ mA to }200\text{ mA}$			10	240	
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$			-1.2		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$			170		μV
Dropout voltage				2		V
Bias current				5	6	mA
Bias current change	$V_I = 27\text{ V to }38\text{ V}$ , $I_O = 5\text{ mA to }350\text{ mA}$	$I_O = 200\text{ mA}$ , $T_J = 0^\circ\text{C to }125^\circ\text{C}$			0.8	mA
					0.5	
Short-circuit output current	$V_I = 35\text{ V}$			240		mA
Peak output current				0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.

**electrical characteristics at specified virtual junction temperature,  $V_I = 10\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†		μA78M05Y			UNIT
			MIN	TYP	MAX	
Output voltage				5		V
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 7\text{ V to }25\text{ V}$		3		mV
		$V_I = 8\text{ V to }25\text{ V}$		1		
Ripple rejection	$V_I = 8\text{ V to }18\text{ V}$ , $I_O = 300\text{ mA}$ , $f = 120\text{ Hz}$			80		dB
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$			20		mV
	$I_O = 5\text{ mA to }200\text{ mA}$			10		
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$			-1		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$			40		μV
Dropout voltage				2		V
Bias current				4.5		mA
Short-circuit output current	$V_I = 35\text{ V}$			300		mA
Peak output current				0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.



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**electrical characteristics at specified virtual junction temperature,  $V_I = 11\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†		μA78M06Y			UNIT	
			MIN	TYP	MAX		
Output voltage			6			V	
Input voltage regulation	I <sub>O</sub> = 200 mA	V <sub>I</sub> = 8 V to 25 V	5			mV	
		V <sub>I</sub> = 9 V to 25 V	1.5				
Ripple rejection	V <sub>I</sub> = 9 V to 19 V,	I <sub>O</sub> = 300 mA,	f = 120 Hz			80	dB
Output voltage regulation	I <sub>O</sub> = 5 mA to 500 mA		20			mV	
	I <sub>O</sub> = 5 mA to 200 mA		10				
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA		−1			mV/°C	
Output noise voltage	f = 10 Hz to 100 kHz		45			μV	
Dropout voltage			2			V	
Bias current			4.5			mA	
Short-circuit output current	V <sub>I</sub> = 35 V		270			mA	
Peak output current			0.7			A	

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.

**electrical characteristics at specified virtual junction temperature,  $V_I = 14\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†		μA78M08Y			UNIT
			MIN	TYP	MAX	
Output voltage			8			V
Input voltage regulation	I <sub>O</sub> = 200 mA	V <sub>I</sub> = 10.5 V to 25 V	6			mV
		V <sub>I</sub> = 11 V to 25 V	2			
Ripple rejection	V <sub>I</sub> = 11.5 V to 21.5 V, I <sub>O</sub> = 300 mA, f = 120 Hz	80			dB	
Output voltage regulation	I <sub>O</sub> = 5 mA to 500 mA		25			mV
	I <sub>O</sub> = 5 mA to 200 mA		10			
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA		−1			mV/°C
Output noise voltage	f = 10 Hz to 100 kHz		52			μV
Dropout voltage			2			V
Bias current			4.6			mA
Short-circuit output current	V <sub>I</sub> = 35 V		250			mA
Peak output current			0.7			A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.

# **μA78M00 SERIES** **POSITIVE-VOLTAGE REGULATORS**

SLVS059D – JUNE 1976 – REVISED JULY 1999

**electrical characteristics at specified virtual junction temperature,  $V_I = 16\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†		μA78M09Y			UNIT	
			MIN	TYP	MAX		
Output voltage			9			V	
Input voltage regulation	I <sub>O</sub> = 200 mA	V <sub>I</sub> = 11.5 V to 26 V	6			mV	
		V <sub>I</sub> = 12 V to 26 V	2				
Ripple rejection	V <sub>I</sub> = 13 V to 23 V,	I <sub>O</sub> = 300 mA,	f = 120 Hz			80	dB
Output voltage regulation	I <sub>O</sub> = 5 mA to 500 mA		25			mV	
	I <sub>O</sub> = 5 mA to 200 mA		10				
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA, T <sub>J</sub> = 0°C to 125°C		–1			mV/°C	
Output noise voltage	f = 10 Hz to 100 kHz		58			μV	
Dropout voltage			2			V	
Bias current			4.6			mA	
Short-circuit output current	V <sub>I</sub> = 35 V		250			mA	
Peak output current			0.7			A	

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.

**electrical characteristics at specified virtual junction temperature,  $V_I = 17\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONST		μA78M10Y			UNIT
			MIN	TYP	MAX	
Output voltage			10			V
Input voltage regulation	I <sub>O</sub> = 200 mA	V <sub>I</sub> = 12.5 V to 28 V	7			mV
		V <sub>I</sub> = 14 V to 28 V	2			
Ripple rejection	V <sub>I</sub> = 15 V to 25 V, I <sub>O</sub> = 300 mA, f = 120 Hz		80			dB
Output voltage regulation	I <sub>O</sub> = 5 mA to 500 mA		25			mV
	I <sub>O</sub> = 5 mA to 200 mA		10			
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA		−1			mV/°C
Output noise voltage	f = 10 Hz to 100 kHz		64			μV
Dropout voltage			2			V
Bias current			4.7			mA
Short-circuit output current	V <sub>I</sub> = 35 V		245			mA
Peak output current			0.7			A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.



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**electrical characteristics at specified virtual junction temperature,  $V_I = 19\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†		μA78M12Y			UNIT
			MIN	TYP	MAX	
Output voltage			12			V
Input voltage regulation	I <sub>O</sub> = 200 mA	V <sub>I</sub> = 14.5 V to 30 V	8			mV
		V <sub>I</sub> = 16 V to 30 V	2			
Ripple rejection	V <sub>I</sub> = 15 V to 25 V, I <sub>O</sub> = 300 mA, f = 120 Hz		80			dB
Output voltage regulation	I <sub>O</sub> = 5 mA to 500 mA		25			mV
	I <sub>O</sub> = 5 mA to 200 mA		10			
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA		−1			mV/°C
Output noise voltage	f = 10 Hz to 100 kHz		75			μV
Dropout voltage			2			V
Bias current			4.8			mA
Short-circuit output current	V <sub>I</sub> = 35 V		240			mA
Peak output current			0.7			A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.

**electrical characteristics at specified virtual junction temperature,  $V_I = 23\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†		μA78M15C			UNIT
			MIN	TYP	MAX	
Output voltage			15			V
Input voltage regulation	I <sub>O</sub> = 200 mA	V <sub>I</sub> = 17.5 V to 30 V	10			mV
		V <sub>I</sub> = 20 V to 30 V	3			
Ripple rejection	V <sub>I</sub> = 18.5 V to 28.5 V,	I <sub>O</sub> = 300 mA,      f = 120 Hz	70			dB
Output voltage regulation	I <sub>O</sub> = 5 mA to 500 mA		25			mV
	I <sub>O</sub> = 5 mA to 200 mA		10			
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA		–1			mV/°C
Output noise voltage	f = 10 Hz to 100 kHz		90			μV
Dropout voltage			2			V
Bias current			4.8			mA
Short-circuit output current	V <sub>I</sub> = 35 V		240			mA
Peak output current			0.7			A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.

# **μA78M00 SERIES** **POSITIVE-VOLTAGE REGULATORS**

SLVS059D – JUNE 1976 – REVISED JULY 1999

**electrical characteristics at specified virtual junction temperature,  $V_I = 29\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†		μA78M20C			UNIT
			MIN	TYP	MAX	
Output voltage			20			V
Input voltage regulation	I <sub>O</sub> = 200 mA	V <sub>I</sub> = 23 V to 35 V	10			mV
		V <sub>I</sub> = 24 V to 35 V	5			
Ripple rejection	V <sub>I</sub> = 24 V to 34 V,      f = 120 Hz,      I <sub>O</sub> = 300 mA		70			dB
Output voltage regulation	I <sub>O</sub> = 5 mA to 500 mA		30			mV
	I <sub>O</sub> = 5 mA to 200 mA		10			
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA		−1.1			mV/°C
Output noise voltage	f = 10 Hz to 100 kHz		110			μV
Dropout voltage			2			V
Bias current			4.9			mA
Short-circuit output current	V <sub>I</sub> = 35 V		240			mA
Peak output current			0.7			A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.

**electrical characteristics at specified virtual junction temperature,  $V_I = 33\text{ V}$ ,  $I_O = 350\text{ mA}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONST		μA78M24Y			UNIT
			MIN	TYP	MAX	
Output voltage			24			V
Input voltage regulation	I <sub>O</sub> = 200 mA	V <sub>I</sub> = 27 V to 38 V	10			mV
		V <sub>I</sub> = 28 V to 38 V	5			
Ripple rejection	V <sub>I</sub> = 28 V to 38 V, I <sub>O</sub> = 300 mA, f = 120 Hz		70			dB
Output voltage regulation	I <sub>O</sub> = 5 mA to 500 mA		30			mV
	I <sub>O</sub> = 5 mA to 200 mA		10			
Temperature coefficient of output voltage	I <sub>O</sub> = 5 mA		−1.2			mV/°C
Output noise voltage	f = 10 Hz to 100 kHz		170			μV
Dropout voltage			2			V
Bias current			5			mA
Short-circuit output current	V <sub>I</sub> = 35 V		240			mA
Peak output current			0.7			A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain  $T_J$  as close to  $T_A$  as possible. Thermal effects must be taken into account separately.



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